

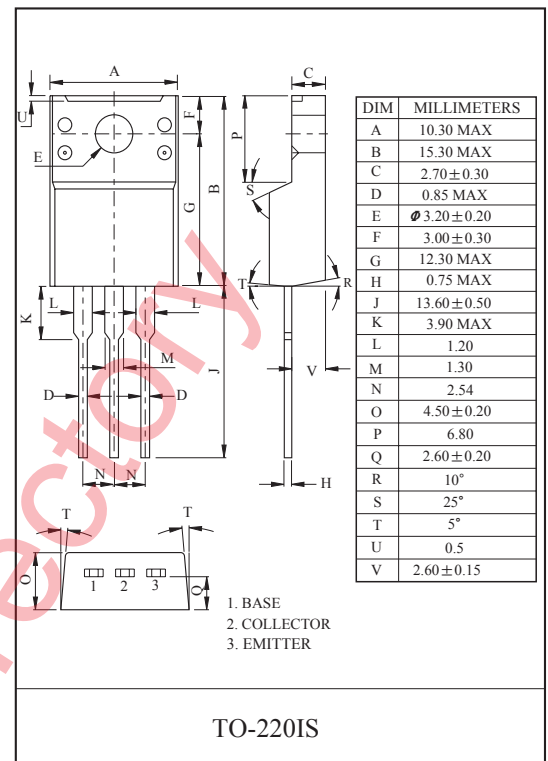
GENERAL PURPOSE APPLICATION.

#### FEATURES

- Complementary to TIP31CF.

#### MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		$V_{CBO}$	-100	V
Collector-Emitter Voltage		$V_{CEO}$	-100	V
Emitter-Base Voltage		$V_{EBO}$	-5	V
Collector Current	DC	$I_C$	-3	A
	Pulse	$I_{CP}$	-5	
Base Current		$I_B$	-1	A
Collector Power Dissipation	Ta=25°C	$P_C$	2	W
	Tc=25°C		25	
Junction Temperature		$T_j$	150	°C
Storage Temperature Range		$T_{stg}$	-55 ~ 150	°C



#### ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Emitter Sustaining Voltage	$V_{CEO(SUS)}$	$I_C=-30mA, I_B=0$	-100	-	-	V
Collector Cut-off Current	$I_{CEO}$	$V_{CE}=-60V, I_B=0$	-	-	-0.3	mA
Collector Cut-off Current	$I_{CES}$	$V_{CE}=-100V, V_{EB}=0$	-	-	-200	μA
Emitter Cut-off Current	$I_{EBO}$	$V_{BE}=-5V, I_C=0$	-	-	-1	mA
DC Current Gain	$h_{FE}$	$V_{CE}=-4V, I_C=-1A$	25	-	-	
		$V_{CE}=-4V, I_C=-3A$	10	-	50	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-3A, I_B=-375mA$	-	-	-1.2	V
Base-Emitter On Voltage	$V_{BE(on)}$	$V_{CE}=-4V, I_C=-3A$	-	-	-1.8	V
Transition Frequency	$f_T$	$V_{CE}=-10V, I_C=-500mA, f=1MHz$	3.0	-	-	MHz

# TIP32CF

